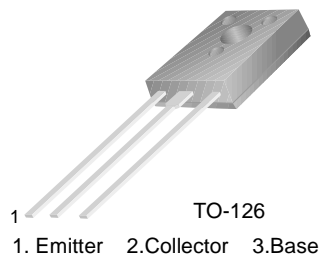


# KSE340

KSE340

## High Voltage General Purpose Applications

- High Collector-Emitter Breakdown Voltage
- Suitable for Transformer
- Complement to KSE350



## NPN Epitaxial Silicon Transistor

### Absolute Maximum Ratings $T_C=25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	300	V
$V_{CEO}$	Collector-Emitter Voltage	300	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current	500	mA
$P_C$	Collector Dissipation ( $T_C=25^{\circ}\text{C}$ )	20	W
$T_J$	Junction Temperature	150	$^{\circ}\text{C}$
$T_{STG}$	Storage Temperature	- 65 ~ 150	$^{\circ}\text{C}$

### Electrical Characteristics $T_C=25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 1\text{mA}, I_B = 0$	300		V
$I_{CBO}$	Collector Cut-off Current	$V_{CB} = 300\text{V}, I_E = 0$		100	$\mu\text{A}$
$I_{EBO}$	Emitter Cut-off Current	$V_{BE} = 3\text{V}, I_C = 0$		100	$\mu\text{A}$
$h_{FE}$	DC Current Gain	$V_{CE} = 10\text{V}, I_C = 50\text{mA}$	30	240	

# Typical Characteristics

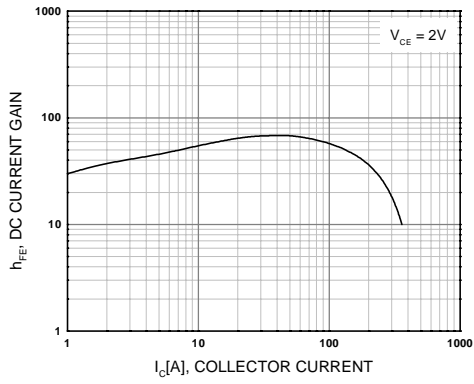


Figure 1. DC current Gain

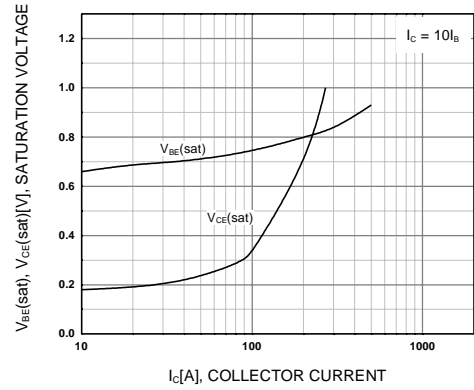


Figure 2. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

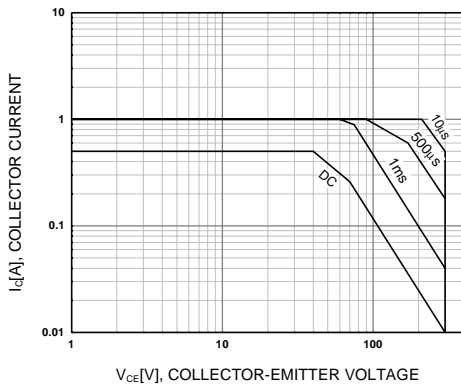


Figure 3. Safe Operating Area

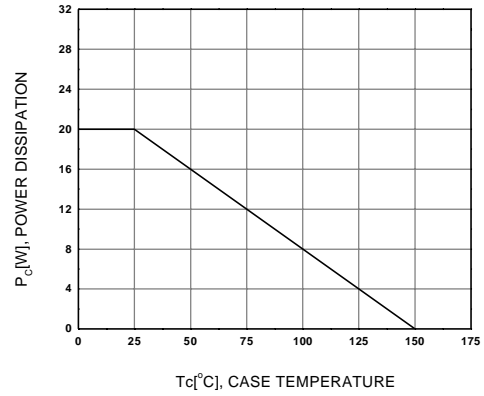


Figure 4. Power Derating

Technical drawing of the 2.28TYP connector showing three views: top, side, and front.

**Top View Dimensions:**

- Overall width:  $8.00 \pm 0.30$
- Overall height:  $14.20 \text{ MAX}$
- Top edge thickness:  $3.90 \pm 0.10$
- Central circular feature diameter:  $\phi 3.20 \pm 0.10$
- Bottom edge thickness:  $0.75 \pm 0.10$
- Internal width (left):  $1.60 \pm 0.10$
- Internal width (right):  $0.75 \pm 0.10$
- Bottom edge thickness (right):  $0.75 \pm 0.10$

**Side View Dimensions:**

- Overall height:  $16.10 \pm 0.20$
- Top edge thickness:  $3.25 \pm 0.20$
- Internal width (left):  $(1.00)$
- Internal width (right):  $(0.50)$
- Bottom edge thickness:  $1.75 \pm 0.20$
- Bottom edge thickness (right):  $0.50^{+0.10}_{-0.05}$

**Front View Dimensions:**

- Overall width:  $2.28 \text{ TYP}$  [ $2.28 \pm 0.20$ ]
- Overall height:  $13.06 \pm 0.30$
- Bottom edge thickness:  $0.75 \pm 0.10$
- Internal width (left):  $1.60 \pm 0.10$
- Internal width (right):  $0.75 \pm 0.10$
- Bottom edge thickness (right):  $0.75 \pm 0.10$

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